

Revision 0.70

## **SINGLE FREQUENCY LASER DIODES Distributed Bragg Reflector Laser with integrated Amplifier**



General Product Information			
Product	Application		
1064 nm DBR Laser	Raman Spectroscopy		
with monolithically integrated Tapered Amplifier (TA)	Metrology		
hermetic 14 Pin Butterfly Housing (RoHS compliant)	Nd:YAG Replacement		
including Thermoelectric Cooler and Thermistor	FDFA Pumping		





Parameter	Symbol	Unit	min	typ	max
Storage Temperature	$T_S$	°C	-40		85
Operational Temperature at Case	$T_{C}$	°C	-20		75
Operational Temperature at Laser Chip	$T_LD$	°C	10		50
Forward Current DBR	$I_{DBR}$	mA			500
Forward Current TA	I <sub>TA</sub>	Α			7.5
Reverse Voltage DBR	$V_{R DBR}$	V			2
Reverse Voltage TA	$V_{RTA}$	V			2
Output Power	$P_{opt}$	W			2.5
TEC Current	I <sub>TEC</sub>	А			2.5
TEC Voltage	$V_{TEC}$	V			5.0

#### Measurement Conditions / Comments

Stress in excess of one of the Absolute Maximum Ratings may damage the laser. Please note that a damaging optical power level may occur although the maximum current is not reached. These are stress ratings only, and functional operation at these or any other conditions beyond those indicated under Recommended Operational Conditions is not implied.

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Absolute Maximum Ratings

Parameter	Symbol	Unit	min	typ	max
Operational Temperature at Case	T <sub>C</sub>	°C	0		50
Operational Temperature at Laser Chip	$T_{LD}$	°C	15	25	35
Forward Current DBR	$I_{DBR}$	mA			450
Forward Current TA	I <sub>TA</sub>	Α			7.0
Output Power	$P_{\text{opt}}$	W			2.0

**Measurement Conditions / Comments** 

### Characteristics

Parameter	Symbol	Unit	min	typ	max
Center Wavelength	$\lambda_{C}$	nm	1063	1064	1065
Spectral Width (FWHM)	$\Delta\lambda$	pm		3	
Sidemode Supression Ratio	SMSR	dB	30		

Measurement Conditions / Comments				
see images on page 4				
apart from mode-hops (see Spectral Map on page 4)				
$P_{opt} = 2 W$				



Revision 0.70

# **SINGLE FREQUENCY LASER DIODES Distributed Bragg Reflector Laser with integrated Amplifier**



Characteristics					cont'd
Parameter	Symbol	Unit	min	typ	max
Temperature Coefficient of Wavelength	dλ / dT	nm / K		0.08	
Current Coefficient of Wavelength	$d\lambda/dI_{DBR}$	nm / mA		0.001	
Current Coefficient of Wavelength	$d\lambda$ / $dI_{TA}$	nm / A		0.035	
Laser Current @ P <sub>opt</sub> = 2 .0 W	I <sub>TA</sub>	А			7.0
Slope Efficiency	η	W/A		0.8	
Threshold Current	$I_{\text{th TA}}$	Α		3	
Divergence parallel (FWHM)	$\Theta_{  }$	mrad		2	
Divergence perpendicular (FWHM)	$\Theta_{\perp}$	mrad		2	
Beam Diameter horizontal (1/e²)	d	mm		1	
Beam Diameter vertical (1/e²)	$d_\perp$	mm		1	
Degree of Polarization	DOP	%		90	

Meas	surement Conditions / Comments
Laser	Forward Current DBR
Laser	Forward Current TA
Ampl	ifier
paral	lel to the base plate of the housing (see p. 3)
perpe	endicular to base plate of the housing (see p. 3
paral	lel to the base plate of the housing (see p. 3)
perpe	endicular to base plate of the housing (see p. 3
P <sub>opt</sub> =	2 W; E field parallel to the base plate

Thermoelectric Cooler					
Parameter	Symbol	Unit	min	typ	max
Current	I <sub>TEC</sub>	А			2.5
Voltage	$U_TEC$	V			5.0
Power Dissipation (total loss at case)	P <sub>loss</sub>	W		10	
Temperature Difference	ΔΤ	K			25

Measurement Conditions / Comments
$P_{\text{opt}} = 2 \text{ W, } \Delta T = 20 \text{ K}$
$P_{opt} = 2 \text{ W, } \Delta T = 20 \text{ K}$
$P_{opt} = 2 \text{ W}, \Delta T = 20 \text{ K}$
$P_{opt} = 2 \text{ W, } \Delta T =  T \text{case - TLD} $

Parameter	Symbol	Unit	min	typ	max
Resistance	R	kΩ		10	
Beta Coefficient	β			3892	
Steinhart & Hart Coefficient A	А			1.1293 x 10	-3
Steinhart & Hart Coefficient B	В			2.3410 x 10	-4
Steinhart & Hart Coefficient C	C			8.7755 x 10	-8

Measurement Conditions / Comments				
$T_{LD} = 25^{\circ} C$				
$R_1  /  R_2 = e^{\beta  (1/T_1  -  1/T_2)} $ at $T_{LD} =$	0° 50° C			
$1/T = A + B(\ln R) + C(\ln R)^3$				
T: temperature in Kelvin				
R: resistance at T in Ohm				

Thermistor (Standard NTC Type)

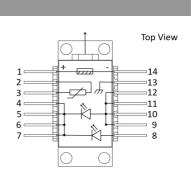


Revision 0.70

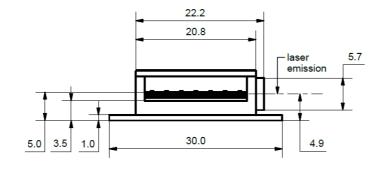
## **SINGLE FREQUENCY LASER DIODES Distributed Bragg Reflector Laser with integrated Amplifier**

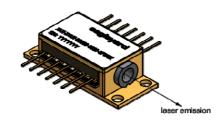


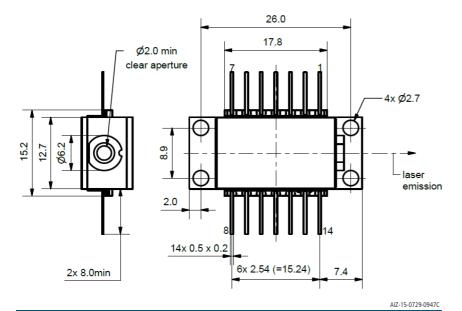
Pin Assignment			
1	Thermoelectric Cooler (+)	14	Thermoelectric Cooler (-)
2	Thermistor		
		13	Case
3	Thermistor	12	Amplifier (Anode)
4	Laser and Amplifier (Cathode)	11	Amplifier (Anode)
5	Laser and Amplifier (Cathode)	10	Amplifier (Anode)
6	Laser and Amplifier (Cathode)	9	Amplifier (Anode)
7	Laser and Amplifier (Cathode)	8	Laser (Anode)



### Package Drawings







Caution. Excessive mechanical stress on the package can lead to a damage of the laser.

instruction manual on www.eagleyard.com



Revision 0.70

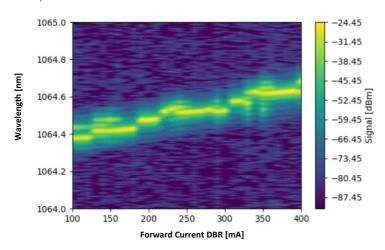
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#### Typical Measurement Results

Spectral Map



Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.

### Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.

The TBR laser is sensitive against optical feedback, so an optical isolator may be required in order to avoid any disturbance of the emission spectrum. Operating at moderate temperatures on proper heat sinks will contribute to a long lifetime of the diode.

Avoid direct and/or indirect exposure to the free running beam. Collimating and focussing the free running beam with optics as common in optical instruments will increase threat to the human eye.

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